NSN 5962-01-246-3686

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-246-3686

Body Length:	
1.110 inches	
Body Width:	
0.410 inches	
Body Height:	
0.180 inches	
Maximum Power Dissipation Rating:	
440.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
W/enable and hermetically sealed and burn in and static operation	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Metal oxide-semiconductor logic	
Input Circuit Pattern:	
16 input	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
5.0 volts power source	
Time Rating Per Chacteristic:	
45.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds	propagation delay time, high to low level
output	
Memory Device Type:	
Ram	
Memory Capacity:	
Unknown	
Test Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufacture	eer standards, etc.).
Terminal Type And Quantity:	
22 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
Yes - demil/mli	

NSN 5962-01-246-3686

Memory Microcircuit - Page 2 of 2

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